## SUM110P04-04L



**Vishay Siliconix** 

# P-Channel 40 V (D-S) 175 °C MOSFET

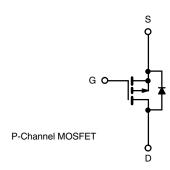
PRODUCT SUMMARY					
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>d</sup>			
-40	0.0042 at $V_{GS}$ = -10 V	-110			
-40	0.0062 at $V_{GS}$ = -4.5 V	-110			

# TO-263

#### FEATURES

- TrenchFET<sup>®</sup> Power MOSFET
- Low thermal resistance
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>





#### Ordering Information:

SUM110P04-04L-E3 (Lead (Pb)-free)

PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V <sub>DS</sub>	-40	v	
Gate-Source Voltage	V <sub>GS</sub>	± 20	v	
Continuous Drain Ourrent (T 175 °C) d	T <sub>C</sub> = 25 °C		-110	
Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>d</sup>	T <sub>C</sub> = 125 °C		-110	A
Pulsed Drain Current	I <sub>DM</sub>	-240	A	
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	-75	
Single Pulse Avalanche Energy <sup>a</sup>		E <sub>AS</sub>	281	mJ
Power Dissinction	T <sub>C</sub> = 25 °C	D	375 <sup>c</sup>	w
Power Dissipation	T <sub>A</sub> = 25 °C <sup>b</sup>	P <sub>D</sub> —	3.75	vv
Operating Junction and Storage Temperature Range	•	T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C

THERMAL RESISTANCE RATINGS						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-Ambient PCB Mount <sup>b</sup>	R <sub>thJA</sub>	40	°C/W			
Junction-to-Case	R <sub>thJC</sub>	0.4				

Notes

- a. Duty cycle  $\leq$  1 %.
- b. When mounted on 1" square PCB (FR-4 material).
- c. See SOA curve for voltage derating.

d. Limited by package.

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = -250 \mu A$	-40				
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	-1		-3		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = -40 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA	
	I <sub>DSS</sub>	$V_{DS}$ = -40 V, $V_{GS}$ = 0 V, $T_{J}$ = 125 °C			-50		
		$V_{DS}$ = -40 V, $V_{GS}$ = 0 V, $T_{J}$ = 175 °C			-250		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -10 V$	-120			А	
	(- )	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -30 A		0.0034	0.0042	Ω	
Drain-Source On-State Resistance a	Р	$V_{GS}$ = -10 V, $I_D$ = -30 A, $T_J$ = 125 °C			0.0063		
Drain-Source On-State Resistance ~	R <sub>DS(on)</sub>	$V_{GS}$ = -10 V, $I_D$ = -30 A, $T_J$ = 175 °C			0.0076		
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -20 \text{ A}$		0.005	0.0062		
Forward Transconductance <sup>a</sup>	<b>g</b> fs	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -30 \text{ A}$	20			S	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			11 200		pF	
Output Capacitance	Coss	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = -25 V, f = 1 MHz		1650			
Reverse Transfer Capacitance	C <sub>rss</sub>			1200			
Total Gate Charge <sup>c</sup>	Qg			235	350	nC	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = -10 \text{ V}, \text{ I}_{D} = -110 \text{ A}$		45			
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			65			
Gate Resistance	Rg			3		Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			25	40	ns	
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = -20 \text{ V}, \text{ R}_{\text{I}} = 0.18 \Omega$		30	45		
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong$ -110 A, $V_{GEN}$ = -10 V, $R_g$ = 2.5 $\Omega$		190	300		
Fall Time <sup>c</sup>	t <sub>f</sub>			110	165		
Source-Drain Diode Ratings and Cha	aracteristics	(T <sub>C</sub> = 25 °C) <sup>b</sup>					
Continuous Current	I <sub>S</sub>				-110		
Pulsed Current	I <sub>SM</sub>				-240	A	
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = -85 A, V <sub>GS</sub> = 0 V		-1	-1.5	V	
Reverse Recovery Time	t <sub>rr</sub>			65	100	ns	
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>	I <sub>F</sub> = -85 A, dl/dt = 100 A/μs		-3.7	-5.6	А	
Reverse Recovery Charge	Q <sub>rr</sub>			0.12	0.28	μC	

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

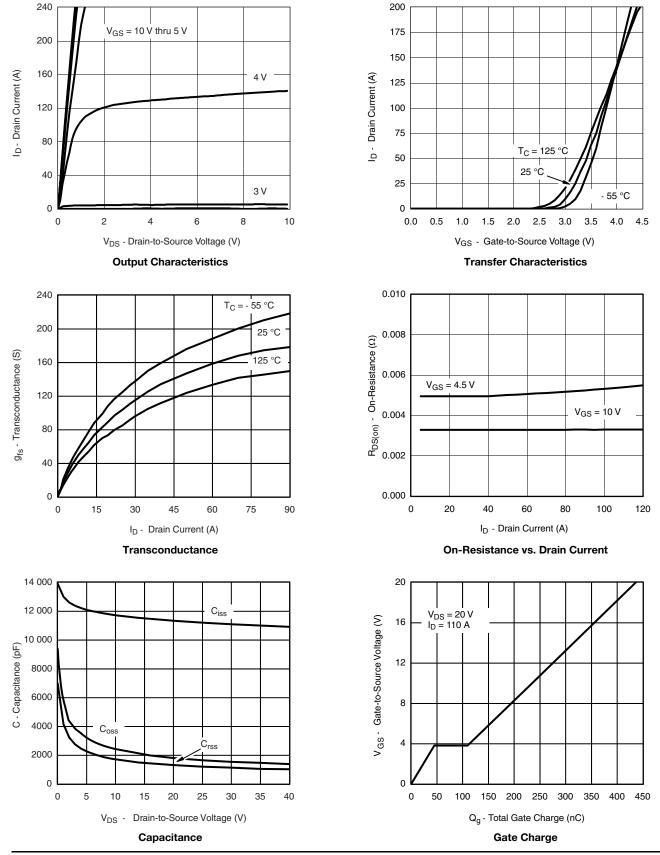
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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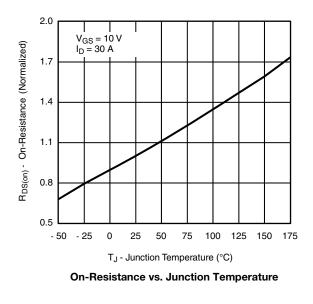
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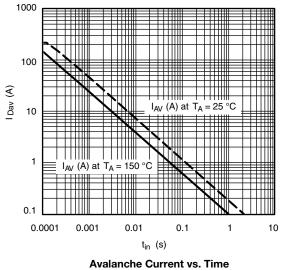


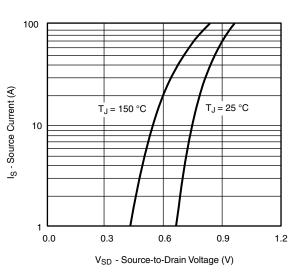


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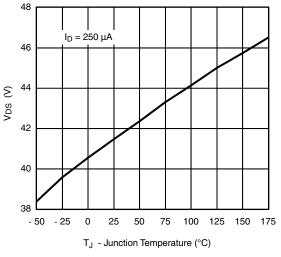
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







Source-Drain Diode Forward Voltage

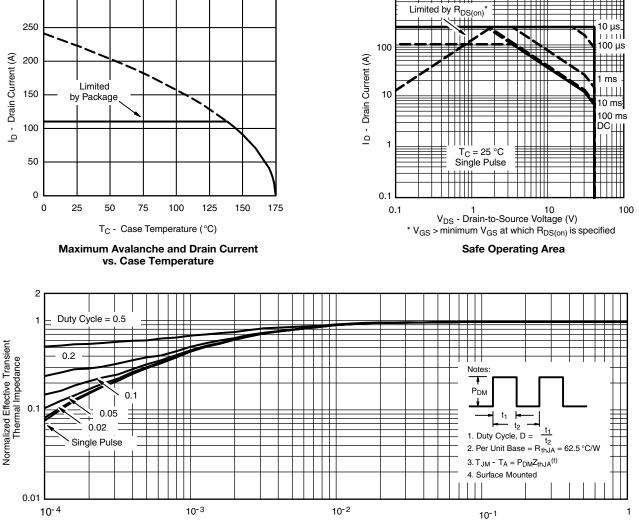


Drain Source Breakdown vs. Junction Temperature

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Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Case

THERMAL RATINGS

reliability data, see www.vishay.com/ppg?72437.

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## SUM110P04-04L

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TO-263 (D<sup>2</sup>PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS			
DIM.		MIN.	MAX.	MIN.	MAX.		
A		0.160	0.190	4.064	4.826		
b		0.020	0.039	0.508	0.990		
b1		0.020	0.035	0.508	0.889		
b2		0.045	0.055	1.143	1.397		
С*	Thin lead	0.013	0.018	0.330	0.457		
	Thick lead	0.023	0.028	0.584	0.711		
c1	Thin lead	0.013	0.017	0.330	0.431		
	Thick lead	0.023	0.027	0.584	0.685		
c2		0.045	0.055	1.143	1.397		
	D	0.340	0.380	8.636	9.652		
D1		0.220	0.240	5.588	6.096		
D2		0.038	0.042	0.965	1.067		
D3		0.045	0.055	1.143	1.397		
D4		0.044	0.052	1.118	1.321		
	E	0.380	0.410	9.652	10.414		
E1		0.245	-	6.223	-		
E2		0.355	0.375	9.017	9.525		
E3		0.072	0.078	1.829	1.981		
	е	0.100	0.100 BSC		2.54 BSC		
К		0.045	0.055	1.143	1.397		
L		0.575	0.625	14.605	15.875		
L1		0.090	0.110	2.286	2.794		
L2		0.040	0.055	1.016	1.397		
L3		0.050	0.070	1.270	1.778		
	L4	0.010 BSC		0.254 BSC			
	М	-	0.002	-	0.050		
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843							

#### Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 % of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. \*: Thin lead is for SUB, SYB.
  - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



## **RECOMMENDED MINIMUM PADS FOR D<sup>2</sup>PAK: 3-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)

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